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Cis-Trans Isomerization During the Electrochemical Doping of Cis-(CH)_x: In Situ ESR Study

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Abstract An in situ Electron Spin Resonance (ESR) study has been carried out during the electrochemical n-type doping of cis-(CH). The cis-trans isomerization is observed after a doping-undoping cycle. The doping level at which the isomerization can be achieved is in the range $\sim 0.3 \rightarrow 0.8$ %. Our results show that this level depends on the rate at which the polymer is doped and that the isomerization process implies a collective motion of the chains at the scale of the fibrils.

INTRODUCTION

The cis-trans isomerization of (CH) $_{\rm X}$ can be attained by a thermal treatment or via a doping-undoping cycle (chemical or electrochemical). No agreement has been reached yet concerning the doping level at which isomerization starts or the level at which it is complete . For this reason we have performed in situ ESR experiments in order to study continuously the kinetics of the isomerization process during the electrochemical doping and undoping of cis-(CH) $_{\rm X}$.

EXPERIMENTAL TECHNIQUE

The electrochemical cell consisted of a cis-(CH) $_{\rm X}$ film as one electrode and a lithium (Li) metal slab as the counter electrode with 1 M LiClO $_{\rm 4}$ in THF as the electrolyte solution. The two electrodes were introduced in a 5 mm ESR tube with the (CH) $_{\rm X}$ electrode in the bottom and the Li electrode 1 cm above.

RESULTS AND DISCUSSION

Figure 1 shows that before doping the ESR spectrum had a broad

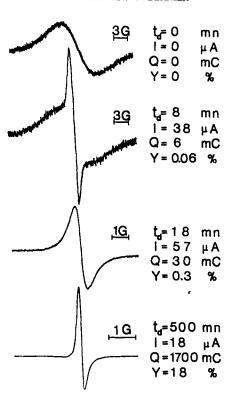


FIGURE 1 Evolution of the ESR signal of cis-(CH)_x during the electrochemical Li doping for various time, current, charge and doping level.

signal (Gaussian shape) with a peak to peak line width \triangle Hpp \sim 7 G characteristic of cis-(CH) $_{\rm x}^{-1}$. A superposition of two signals (broad with \triangle Hpp \sim 7 G and narrow with \triangle Hpp \sim 1 G) has been observed for a doping level as low as y \sim 0.06 %. The superposition is due to the inhomogeneous distribution of current density on the (CH) $_{\rm x}$ film and so of the dopant distribution (the upper part of the film being more doped than the lower) as a consequence of the geometry of the cell. For doping levels higher than y $_{\rm i}$ (y $_{\rm i}^{\sim}$ 0.3 to 0.8 % depending on the experimental conditions) the broad signal completely disappeared and the ESR spectrum consisted of a single narrow line

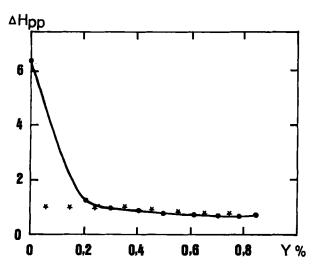


FIGURE 2 The variation of △ Hpp of cis-(CH) with the doping level when •doping ★ undoping

(Lorentzian shape) with △Hpp ~0.8 G characteristic of trans (CH) $_{v}^{1,3,4}$. The variation of Δ Hpp with the doping level is shown in Figure 2. The doped film (y ≈ 0.9 %) could be undoped by applying the potential characteristic of the parent (CH). At the end of the undoping process, the ESR spectrum had the same Lorentzian shape and the same peak to peak line width ~ 0.8 G as in the doped case. The ESR intensity (undoped) was substantially smaller than in the doped case but not significantly different from the intensity of the initial cis-rich-(CH). The sudden decrease of Δ Hpp from \sim 7 G to ~0.8 G when doping is attributed to the isomerization process9 and the constant value of △Hpp ~0.8 G during undoping suggest that a state of complete or almost complete isomerization has been reached. y, is then the doping level at which the isomerization is achieved and its value (0.3 to 0.8 %) is comparable with the value 0.5 % reported by Mihaly $et al^5$. The short doping time (low doping level) reported by François et al and Rachdi et al for the isomerization is also consistent with our result.

On the other hand, our value is in strong apparent disagreement with Chung et al 2 , Feldblum et al 6 , Hoffman et al 7 and Tanaka et al 8 who have deduced that a high concentration ~ 6 % is required for a complete isomerization. We think that this is only an apparent disagreement due to differences in doping techniques.

Two very important points must be clarified: 3,4

- Chemical doping and our electrochemical doping were performed continuously. In this case the system is permanently far from equilibrium for high doping rates or high current densities. On the contrary optical measurements 2,6-8 used a step by step electrochemical process. During each step the system was close to its equilibrium and consequently current densities were small.
- Preliminary results show that the value of the doping level y_i depends on the doping current $I(y_i)$ increases when I decreases). Taking into account these remarks we suggest that the rate at which the polymer is doped is of prime importance for the definition of the doping level y_i at which the isomerization is achieved. We propose the following model to explain our experimental results:
- * For short time, as the electrochemical doping is a surface effect, the majority of the charges injected at the surface of the fibrils has no time to diffuse inside the fibrils (the diffusion coefficient of Li † in the solid phase is \sim 5 X 10 $^{-18}$ cm 2 sec $^{-1}$ 9).
- * There is a given concentration of dopant ions at the surface of the fibrils (corresponding roughly to one dopant per chain of $(CH)_{x}^{9}$) at which the isomerization can occur as a collective process i.e. for the whole volume of the fibrils.
- * For high doping current values, this concentration can be attained very rapidly (consequently at very low doping level) and the isomerization can be achieved.
- * The doping level (obtained as a mean value over the whole sample) at which the isomerization can be achieved y_i is much less than the local dopant concentration close to the surface of the fibril.

* When the doping is performed very slowly the collective motion of the chains cannot be triggered. Parts of the fibrils which are already isomerized are preferentially doped and a total isomerization is reached only for high dopant concentration.

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